

NOT RECOMMENDED FOR NEW DESIGNS RECOMMENDED REPLACEMENT PART ISL55014

ISL55011

MMIC Silicon Bipolar Broadband Amplifier

FN6218 Rev 0.00 May 22, 2006

The ISL55005, ISL55007, ISL55008 and ISL55009, ISL55010, ISL55011 constitute a family of high performance gain blocks featuring a Darlington configuration using high f_t transistors and excellent thermal performance. They are an ideal choice for DVB-S LNB cable receiver applications.

ISL55005, ISL55007, ISL55008 offer higher OIP3 performance while the ISL55009, ISL55010, ISL55011 offer lower operating supply currents.

ISL55005 and ISL55009 match a 75 Ω source to a 50 Ω load. ISL55007 and ISL55010 match a 75 Ω source to a 75 Ω load. ISL55008 and ISL55011 match a 50 Ω source to a 50 Ω load.

Ordering Information

| PART NUMBER (Note) | PART MARKING | TAPE & REEL | PACKAGE (Pb-Free) | PKG. DWG.# |
|--------------------------|-----------------|-------------|----------------------|---------------|
| ISL55011IEZ-T7 | CBH | 7" (3k ncs) | 6 Ld SC-70 | P6.049 |

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

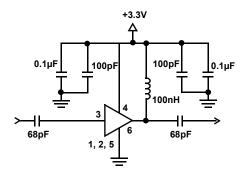
Features

- Input impedance of 50Ω
- Output impedance of 50Ω
- · Noise figure of 3.9dB
- · OIP3 of 10dBm
- · Low supply current of 14mA
- · Low input and output return losses
- · Pb-free plus anneal available (RoHS compliant)

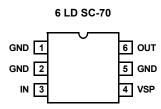
Applications

- · LNB and LNB-T line amplifiers
- · IF gain blocks for satellite and terrestrial HDTV STBs
- · PA driver amplifier
- · Wireless data, satellite
- · Bluetooth/WiFi
- · Satellite locator and signal strength meters

Typical Application Circuit



Pinout



Absolute Maximum Ratings (T_A = 25°C)

| Supply Voltage from VSP to GND 6V | Storage Temperature65°C to +125°C |
|--|---|
| Input Voltage | Operating Junction Temperature |
| Power Dissipation See Packging Information Section | ESD Rating |
| Ambient Operating Temperature | Human Body Model (Per MIL-STD-883 Method 3015.7)3000V |
| | Machine Model (Per EIAJ ED-4701 Method C-111) 300V |

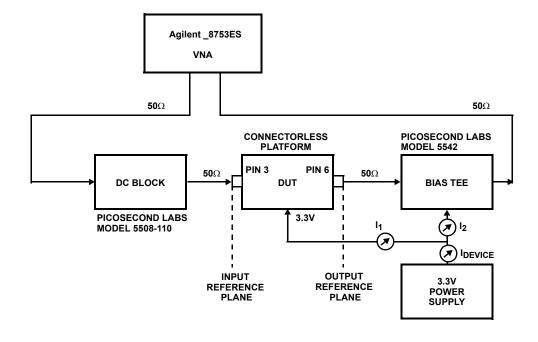
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications VSP = +3.3V, Zrsc = Zload = 50Ω , TA = 25°C, unless otherwise specified.

| PARAMETER | DESCRIPTION | CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|------------------------------------|-------------------------|------|------|------|------|
| Gt S | Small Signal Gain | 1.0GHz | 13.4 | 14.4 | 15.4 | dB |
| | | 1.5GHz | 13.3 | 14.3 | 15.3 | dB |
| | | 2.0GHz | 13.1 | 14.1 | 15.1 | dB |
| P1dB Ou | Output Power at 1dB Compression | 1.0GHz | -0.8 | 1.2 | 3.2 | dBm |
| | | 2.0GHz | -0.7 | 0.8 | 2.3 | dBm |
| OIP3 | Output Third Order Intercept Point | 1.0GHz | | 10.9 | | dBm |
| | | 2.0GHz | | 10.3 | | dBm |
| BW | 3dB Bandwidth | 3dB below Gain @ 500MHz | | 3.4 | | GHz |
| IRL | Input Return Loss | 1.0GHz | | 11.1 | | dB |
| ORL | Output Return Loss | 1.0GHz | | 13.5 | | dB |
| RISOL | Reverse Isolation | 2.0GHz | | 19.6 | | dB |
| NF | Noise Figure | 2.0GHz | | 3.9 | | dB |
| ID | Device Operating Current | | 11.5 | 13.7 | 15.5 | mA |

Device Test Setup





Typical Performance Curves 50Ω environment

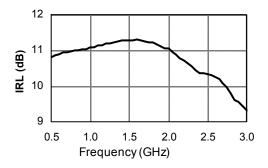


FIGURE 1. INPUT RETURN LOSS vs FREQUENCY

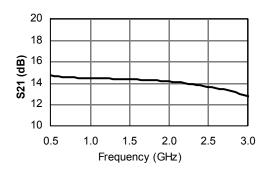


FIGURE 3. |S21| vs FREQUENCY

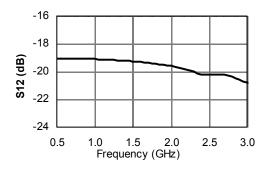


FIGURE 5. |S12| vs FREQUENCY

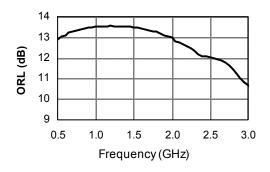


FIGURE 2. OUTPUT RETURN LOSS vs FREQUENCY

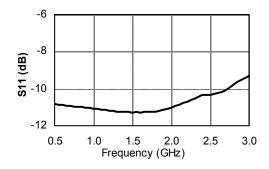


FIGURE 4. |S11| vs FREQUENCY

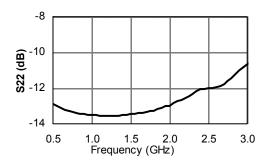
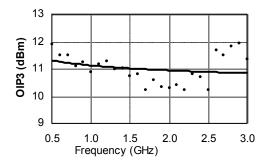


FIGURE 6. |S22| vs FREQUENCY

Typical Performance Curves 50Ω environment (Continued)



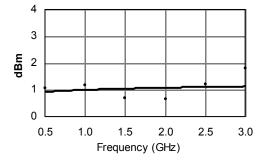


FIGURE 7. OIP3 vs FREQUENCY

FIGURE 8. P1dB vs FREQUENCY

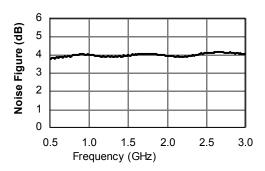


FIGURE 9. NOISE FIGURE vs FREQUENCY

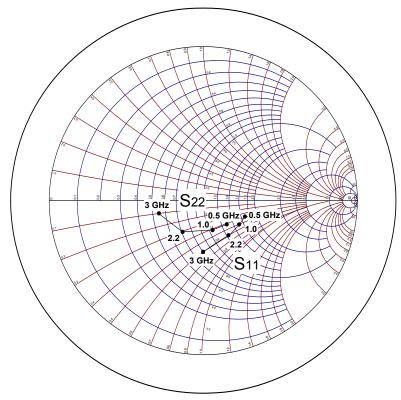


FIGURE 10. S11 AND S22 vs FREQUENCY



Packaging Information

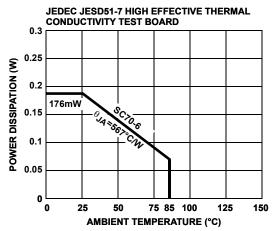
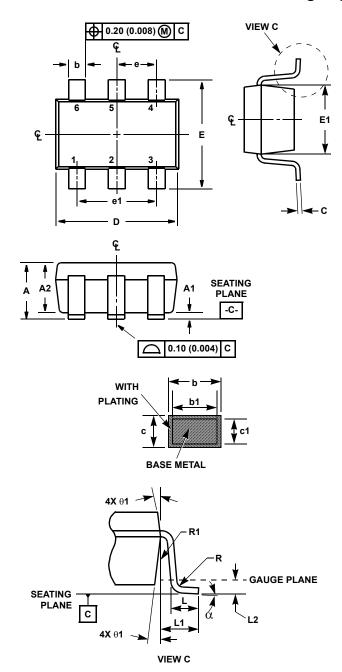


FIGURE 11. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

Small Outline Transistor Plastic Packages (SC70-6)



P6.049
6 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

| | INCHES | | MILLIMETERS | | | |
|--------|------------|----------------|-------------|----------------|-------|--|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES | |
| Α | 0.031 | 0.043 | 0.80 | 1.10 | - | |
| A1 | 0.000 | 0.004 | 0.00 | 0.10 | - | |
| A2 | 0.031 | 0.039 | 0.00 | 1.00 | - | |
| b | 0.006 | 0.012 | 0.15 | 0.30 | - | |
| b1 | 0.006 | 0.010 | 0.15 | 0.25 | | |
| С | 0.003 | 0.009 | 0.08 | 0.22 | 6 | |
| c1 | 0.003 | 0.009 | 0.08 | 0.20 | 6 | |
| D | 0.073 | 0.085 | 1.85 | 2.15 | 3 | |
| Е | 0.071 | 0.094 | 1.80 | 2.40 | - | |
| E1 | 0.045 | 0.053 | 1.15 | 1.35 | 3 | |
| е | 0.0256 Ref | | 0.65 Ref | | - | |
| e1 | 0.051 | 2 Ref | 1.30 Ref | | - | |
| L | 0.010 | 0.018 | 0.26 | 0.46 | 4 | |
| L1 | 0.017 Ref. | | 0.420 Ref. | | | |
| L2 | 0.006 BSC | | 0.15 BSC | | | |
| N | 6 | | 6 | | 5 | |
| R | 0.004 | - | 0.10 | - | | |
| R1 | 0.004 | 0.010 | 0.15 | 0.25 | | |
| α | 0° | 8 ⁰ | 0° | 8 ⁰ | - | |

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NOTES:

- 1. Dimensioning and tolerance per ASME Y14.5M-1994.
- 2. Package conforms to EIAJ SC70 and JEDEC MO203AB.
- 3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
- 4. Footlength L measured at reference to gauge plane.
- 5. "N" is the number of terminal positions.
- 6. These Dimensions apply to the flat section of the lead between 0.08mm and 0.15mm from the lead tip.
- 7. Controlling dimension: MILLIMETER. Converted inch dimensions are for reference only

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